

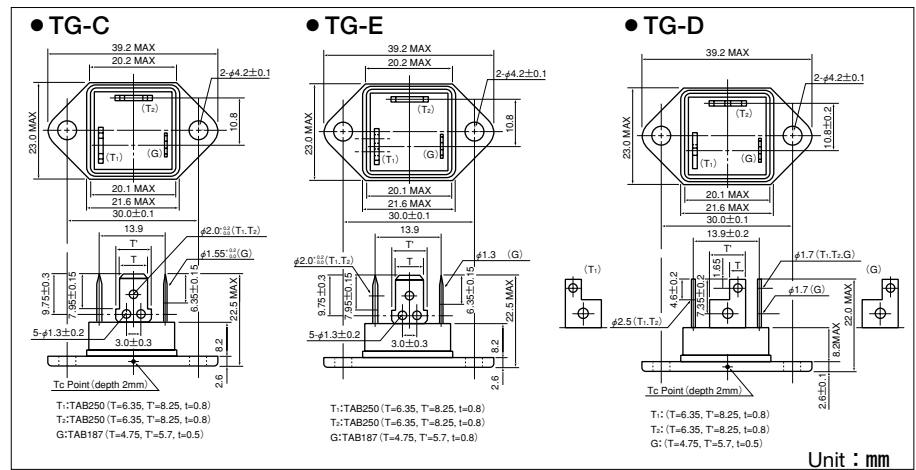
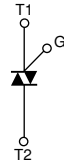
# TRIAC (ISOLATED TYPE)

# TG35C/E/D

UL;E76102 (M)

TG35C/E/D are isolated molded triacs suitable for wide range of applications like copier, microwave oven, solid state switch, motor control, light control and heater control.

- $I_T(AV)$  35A
- High surge capability 330A
- Isolated Nounting (AC2500V)
- Tab Terminals



## Maximum Ratings

( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Item	Ratings		Unit
		TG35C40	TG35C60	
$V_{DRM}$	Repetitive Peak Off-State Voltage	400	600	V

Symbol	Item	Conditions	Ratings	Unit
$I_{T(RMS)}$	R.M.S. On-State Current	$T_c=58^\circ\text{C}$	35	A
$I_{TSM}$	Surge On-State Current	One cycle, 50Hz/60Hz, peak, non-repetitive	300/330	A
$I^2t$	$I^2t$	Value for one cycle of surge current	450	$\text{A}^2\text{S}$
$P_{GM}$	Peak Gate Power Dissipation		10	W
$P_{G(AV)}$	Average Gate Power Dissipation		1	W
$I_{GM}$	Peak Gate Current		3	A
$V_{GM}$	Peak Gate Voltage		10	V
$di/dt$	Critical Rate of Rise of On-State Current	$I_G=100\text{mA}$ , $T_j=25^\circ\text{C}$ , $V_D=1/2V_{DRM}$ , $dI_G/dt=1\text{A}/\mu\text{s}$	50	$\text{A}/\mu\text{s}$
$T_j$	Operating Junction Temperature		-25 to +125	$^\circ\text{C}$
$T_{stg}$	Storage Temperature		-40 to +125	$^\circ\text{C}$
$V_{iso}$	Isolation Breakdown Voltage (R.M.S.)	A.C.1 minute	2500	V
	Mounting Torque (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)	$\text{N}\cdot\text{m}$ ( $\text{kgf}\cdot\text{cm}$ )
	Mass	Typical value (Excluding bolt, nut and wrapping material)	23	g

## Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
$I_{DRM}$	Repetitive Peak Off-State Current, max	$V_D=V_{DRM}$ , Single phase, half wave, $T_j=125^\circ\text{C}$	5	mA
$V_{TM}$	Peak On-State Voltage, max	On-State Current ( $\sqrt{2} \times I_{T(RMS)}$ ), Inst. measurement	1.4	V
$I_{GT1}^+$	Gate Trigger Current, max	$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	50	mA
$I_{GT1}^-$		$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	50	
$I_{GT3}^+$		—	—	
$I_{GT3}^-$		$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	50	
$V_{GT1}^+$	Gate Trigger Voltage, max	$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	3	V
$V_{GT1}^-$		$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	3	
$V_{GT3}^+$		—	—	
$V_{GT3}^-$		$T_j=25^\circ\text{C}$ , $I_T=1\text{A}$ , $V_D=6\text{V}$	3	
$V_{GD}$	Non-Trigger Gate Voltage, min	$T_j=125^\circ\text{C}$ , $V_D=1/2V_{DRM}$	0.2	V
$t_{gt}$	Turn On Time, max.	$I_{T(RMS)}$ , $I_G=100\text{mA}$ , $V_D=1/2V_{DRM}$ , $T_j=25^\circ\text{C}$ , $dI_G/dt=1\text{A}/\mu\text{s}$	10	V
$dv/dt$	Critical Rate of Rise on-State Voltage, min.	$T_j=125^\circ\text{C}$ , $V_D=2/3V_{DRM}$ , Exponential wave.	20	$\text{V}/\mu\text{s}$
$(dv/dt)_c$	Critical Rate of Rise off-State Voltage at commutation, min	$T_j=125^\circ\text{C}$ , $V_D=2/3V_{DRM}$ , $(di/dt)_c=15\text{A}/\text{ms}$	5	$\text{V}/\mu\text{s}$
$I_H$	Holding Current, typ.	$T_j=25^\circ\text{C}$	30	mA
$R_{th(j-c)}$	Thermal Impedance, max	Junction to case	1.5	$^\circ\text{C}/\text{W}$

